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MOSFET - N-Channel Shielded Gate PowerTrench[®]

150 V, 31 mΩ, 31 A

NTMFS034N15MC

Features

- Small Footprint (5 x 6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low QG and Capacitance to Minimize Driver Losses
- 100% UIL Tested
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Synchronous Rectification
- AC-DC and DC-DC Power Supplies
- AC-DC Adapters (USB PD) SR
- Load Switch

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Parameter		Symbol	Value	Unit	
Drain-to-Source Voltage		V _{DSS}	150	V	
Gate-to-Source Voltage		V _{GS}	±20	V	
Continuous Drain Current $R_{\theta JC}$ (Note 2)	Steady	T _C = 25°C	۱ _D	31	A
Power Dissipation $R_{\theta JC}$ (Note 2)	State		P _D	62.5	W
Continuous Drain Current R _{θJA} (Notes 1, 2)	Steady State	T _A = 25°C	Ι _D	6.1	A
Power Dissipation $R_{\theta JA}$ (Notes 1, 2)	Sidle		P _D	2.5	W
Pulsed Drain Current	$T_{\rm C} = 25^{\circ}$	C, t _p = 100 μs	I _{DM}	131	А
Operating Junction and Storage Temperature Range			T _J , T _{stg}	–55 to +150	°C
Single Pulse Drain-to-Source Avalanche Energy ($I_L = 6 A_{pk}, L = 3 mH$)			E _{AS}	54	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface-mounted on FR4 board using a 1 in², 2 oz. Cu pad.

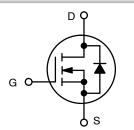
The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.



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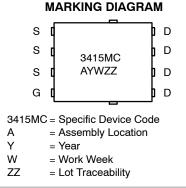
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V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
150 V	31 mΩ @ 10 V	31 A



N-CHANNEL MOSFET





ORDERING INFORMATION

Device	Package	Shipping [†]		
NTMFS034N15MC	Power 56	3000 / Tape		
(Pb-Free/Halogen Free)	(PQFN8)	& Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit	
Junction-to-Case - Steady State (Note 2)	$R_{ extsf{ heta}JC}$	2.0	°C/W	
Junction-to-Ambient - Steady State (Notes 1, 2)	$R_{ hetaJA}$	50		

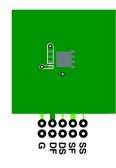
ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 μ A		150			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J	$I_D = 250 \ \mu A$, ref to $25^{\circ}C$			86		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = 120 V	T _J = 25°C			1.0	μΑ
Gate-to-Source Leakage Current	I _{GSS}	V_{DS} = 0 V, V_{GS} = ±20 V				±100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 7$	70 μA	2.5		4.5	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J	$I_D = 70 \ \mu A$, ref to	25°C		-7.7		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V, I _D =	13 A		25	31	mΩ
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 8 V, I _D = 6 A			27	36.5	mΩ
Forward Transconductance	9 _{FS}	V _{DS} = 10 V, I _D = 13 A			27		S
CHARGES, CAPACITANCES & GATE RESIS	TANCE						
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 75 V			905		
Output Capacitance	C _{OSS}				270		pF
Reverse Transfer Capacitance	C _{RSS}				5		
Gate-Resistance	R _G				0.6	1.2	Ω
Total Gate Charge	Q _{G(TOT)}				12		
Threshold Gate Charge	Q _{G(TH)}				3.1		
Gate-to-Source Charge	Q _{GS}	V_{GS} = 10 V, V_{DS} = 75 V; I_{D} = 13 A			4.8		nC
Gate-to-Drain Charge	Q _{GD}				1.8		
Plateau Voltage	V _{GP}				5.4		V
Output Charge	Q _{OSS}	V _{DD} = 75 V, V _{GS} = 0 V			32		nC
SWITCHING CHARACTERISTICS (Note 3)							
Turn-On Delay Time	t _{d(ON)}				12		
Rise Time	t _r	V_{GS} = 10 V, V_{DD} = 75 V, I_{D} = 13 A, R_{G} = 6 Ω			2.2		ns
Turn-Off Delay Time	t _{d(OFF)}				14		
Fall Time	t _f				2.5		
DRAIN-SOURCE DIODE CHARACTERISTIC	S	-			-	-	-
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 \text{ V}, \text{ I}_{S} = 13 \text{ A}$	$T_J = 25^{\circ}C$		0.87	1.2	V
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, V _{DD} = 75 V dI _S /dt = 300 A/μs, I _S = 13 A			41		ns
Reverse Recovery Charge	Q _{RR}				126		nC
Reverse Recovery Time	t _{RR}	V_{GS} = 0 V, V_{DD} = 75 V dI _S /dt = 1000 A/µs, I _S = 13 A			22		ns
Reverse Recovery Charge	Q _{RR}				164		nC

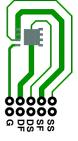
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NOTES:

- Switching characteristics are independent of operating junction temperatures.
 R_{θJA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 × 1.5 in. board of FR-4 material. R_{θCA} is determined by the user's board design.

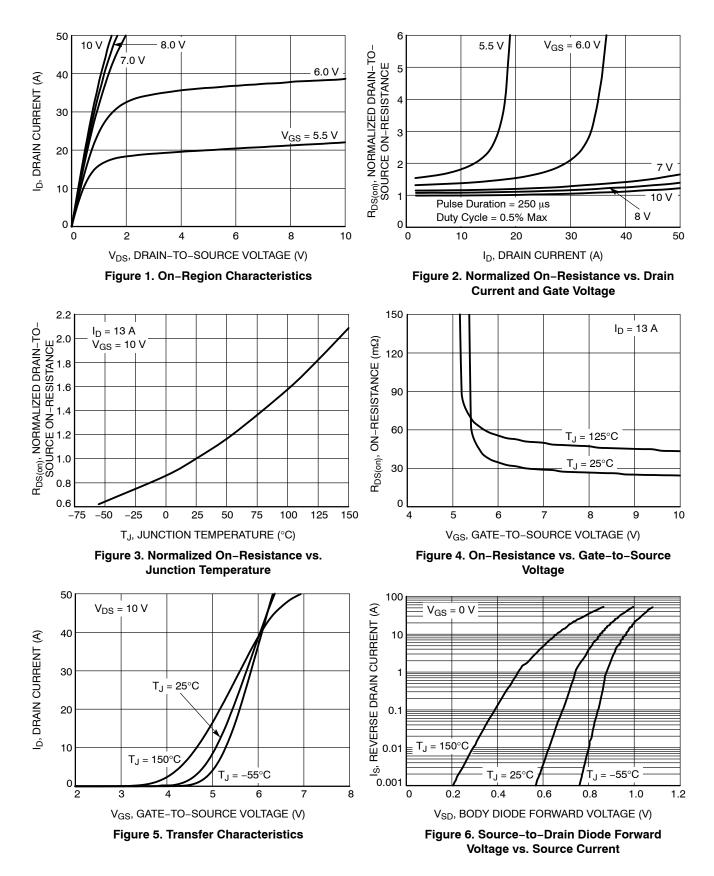


a) 50°C/W when mounted on a 1 in² pad of 2 oz copper.

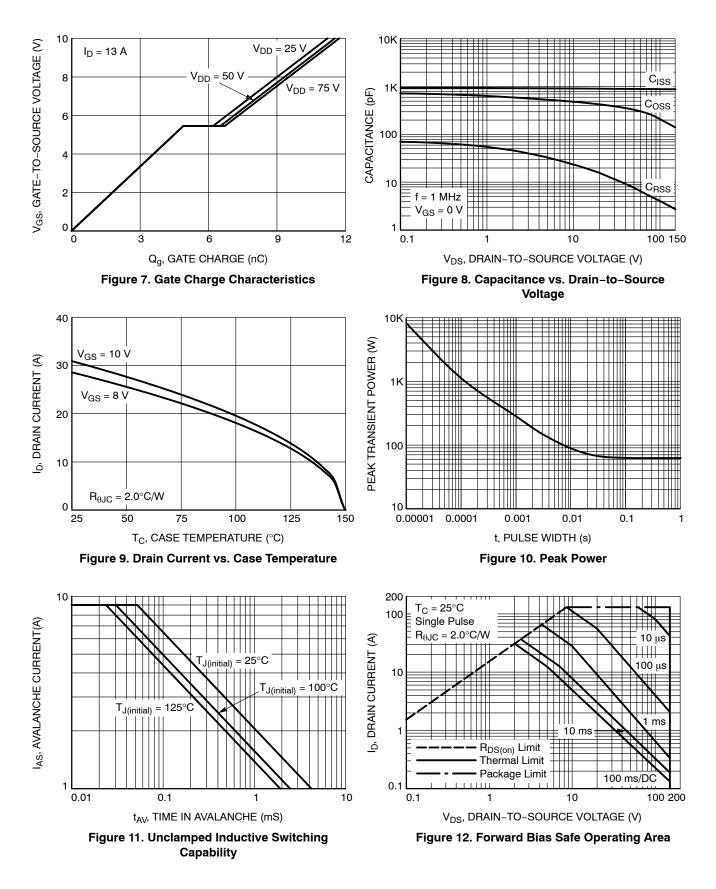


b) $125^{\circ}C/W$ when mounted on a minimum pad of 2 oz copper.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

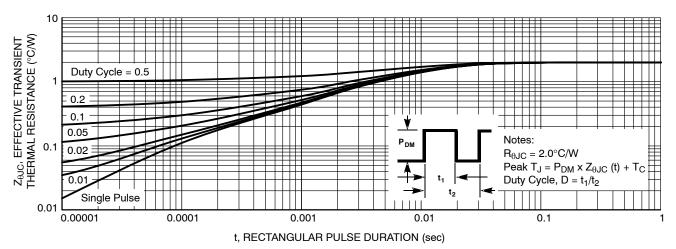
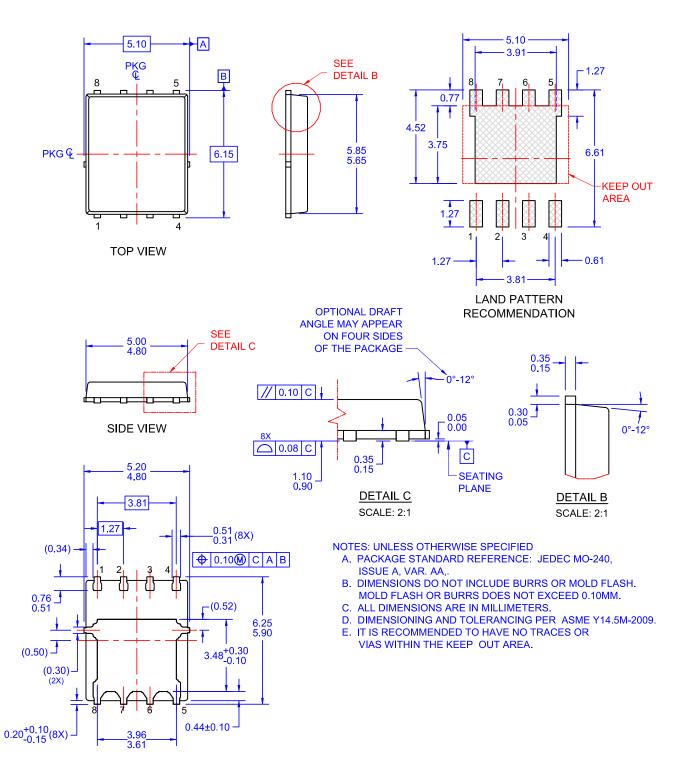


Figure 13. Transient Thermal Impedance

PACKAGE DIMENSIONS

PQFN8 5X6, 1.27P CASE 483AE ISSUE A



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